











TPS63050, TPS63051

SLVSAM8D-JULY 2013-REVISED AUGUST 2019

# TPS6305x Single Inductor Buck-Boost With 1-A Switches and Adjustable Soft Start

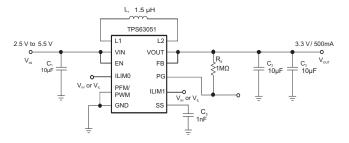
## **Features**

- Real buck or boost with seamless transition between buck and boost mode
- 2.5 V to 5.5 V Input voltage range
- 0.5-A Continuous output current:  $V_{IN} \ge 2.5 \text{ V}$ ,  $V_{OUT} = 3.3 \text{ V}$
- Adjustable and fixed output voltage version
- Efficiency > 90% in boost mode and > 95% in buck mode
- 2.5-MHz Typical switching frequency
- Adjustable average input current limit
- Adjustable soft-start time
- Device quiescent current < 60 μA
- Automatic power save mode or forced PWM mode
- Load disconnect during shutdown
- Overtemperature protection
- Small 1.6mm x 1.2mm, 12-pin WCSP and 2.5mm x 2.5mm 12-pin HotRod™ QFN package
- Create a custom design using the:
  - TPS63050 With the WEBENCH® Power Designer
  - TPS63051 With the WEBENCH<sup>®</sup> Power Designer

# Applications

- Cellular and smart phones
- Tablets PC
- PC and smart phone accessories
- Battery powered applications
- Smart grid/smart meter

## Simplified Schematic (WCSP)



# 3 Description

The TPS6305x family of devices is a high efficiency, low quiescent-current buck-boost converter, suitable for applications where the input voltage is higher or lower than the output.

Continuous output current can go as high as 500 mA in boost mode and as high as 1 A in buck mode. The maximum average current in the switches is limited to a typical value of 1 A. The TPS6305x family of devices regulate the output voltage over the complete input voltage range by automatically switching between buck or boost mode depending on the input voltage, ensuring seamless transition between modes.

The buck-boost converter is based on a fixedfrequency, pulse-width-modulation (PWM) controller using synchronous rectification to obtain the highest efficiency. At low load currents, the converter enters Power Save Mode to maintain high efficiency over the complete load current range.

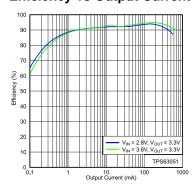
The PFM/PWM pin allows the user to select between automatic-PFM/PWM mode operation and forced-PWM operation. During PWM mode a fixed-frequency of typically 2.5 MHz is used. The output voltage is programmable using an external resistor divider, or is fixed internally on the chip. The converter can be disabled to minimize battery drain. During shutdown, the load is disconnected from the battery. The device is packaged in a 12-pin DSBGA and in a 12-pin HotRod package.

## Device Information(1)

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)   |
|-------------|------------|-------------------|
| TPS63050    | DSBGA (12) | 1.56 mm x 1.16 mm |
| TPS63051    | VQFN (12)  | 2.50 mm × 2.50 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### **Efficiency vs Output Current**





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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision C (July 2015) to Revision D   | Page              |
|---|-------------------|
| Added Webench links to the data sheet   | 1                 |
| Changed the Pin Configurations  | 4                 |
| • Changed the quiescent current $V_{IN}$ max value From: 60 $\mu A$ To: 65 $\mu A$ in the <i>Electrical Characteristics</i>       | 6                 |
| • Added Note: Conditions: $T_J = -40$ °C to 85°C To the quiescent current and shutdown current in the <i>Elec Characteristics</i> |                   |
| Changes from Revision B (April 2015) to Revision C  | Page              |
| Added new package option to Features  | 1                 |
| Added VQFN package to Device Information table  | 1                 |
| Added HotRod Pin Configuration and Functions  | 4                 |
| Added Parameter Measurement Circuit for HotRod package option   | 15                |
| Changes from Revision A (February 2014) to Revision B   | Page              |
| Changed Description section   | 1                 |
| Changed graphic image   | 1                 |
| Changed Ordering Information table To: Device Comparison Table  | 4                 |
| • Changed "Handling Ratings" table to "ESD Rating" table and moved T <sub>stg</sub> spec to the Absolute Maximum                  | n Ratings table 5 |





| Cł | hanges from Original (July 2013) to Revision A   | age  |
|----|--|------|
| •  | Added Device Information and ESD Rating tables, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section | 1    |
| •  | Added TPS63050 device specifications and description throughout data sheet   | 1    |
| •  | Changed Figure 34, PCB Layout  | . 23 |
| •  | Changed Figure 35, PCB Layout  | . 23 |

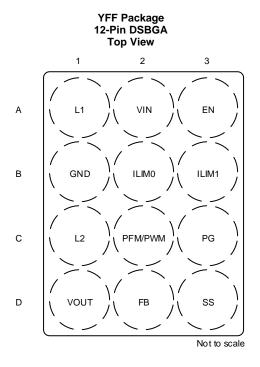


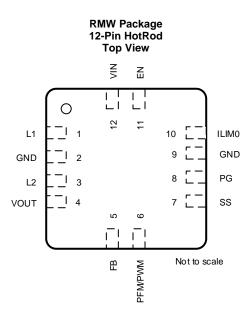
# 5 Device Comparison Table

| PART NUMBER (1) | V <sub>OUT</sub> |
|-----------------|------------------|
| TPS63050        | Adjustable       |
| TPS63051        | 3.3 V            |

(1) For all available packages, see the orderable addendum at the end of the datasheet

# 6 Pin Configuration and Functions





## **Pin Functions**

|         | PIN  |         | 1/0 | DESCRIPTION   |  |
|---------|------|---------|-----|---|--|
| NAME    | WCSP | HotRod  | 1/0 |   |  |
| EN      | A3   | 11      | - 1 | Enable input. (1 enabled, 0 disabled). It must not be left floating   |  |
| FB      | D2   | 5       | I   | Voltage feedback of adjustable versions, must be connected to VOUT on fixed output voltage versions1  |  |
| GND     | B1   | 2,9     |     | ound for Power stage and Control stage  |  |
| ILIMO   | B2   | 10      | I   | grammable inrush current limit input works together with I <sub>LIM1</sub> . See table on page 1. ust not be left floating                  |  |
| ILIM1   | В3   | See (1) | I   | grammable inrush current limit input works together with I <sub>LIM0</sub> .  Efficiency vs Output Current on page 1. Do not leave floating |  |
| L1      | A1   | 1       |     | Connection for Inductor   |  |
| L2      | C1   | 3       |     | Connection for Inductor   |  |
| PFM/PWM | C2   | 6       | I   | 0 for PFM mode 1 for forced PWM mode. It must not be left floating  |  |
| PG      | C3   | 8       | 0   | Power good open drain output  |  |
| SS      | D3   | 7       | I   | Adjustable Soft-Start. If left floating default soft-start time is set  |  |
| VIN     | A2   | 12      | - 1 | Supply voltage for power stage and control stage  |  |
| VOUT    | D1   | 4       | 0   | Buck-boost converter output   |  |

(1) Only available with DSBGA package, for VQFN package ILIM1 is internally connected to voltage level > V<sub>IH</sub>



# 7 Specifications

# 7.1 Absolute Maximum Ratings

over junction temperature range (unless otherwise noted) (1)

|   |   | MIN  | MAX | UNIT |  |
|---|---|------|-----|------|--|
| Voltage <sup>(2)</sup>                        | V <sub>IN</sub> , L1, EN, V <sub>OUT</sub> , FB, V <sub>IN</sub> A, PFM/PWM | -0.3 | 7   |      |  |
|   | L2 <sup>(3)</sup>   | -0.3 | 7   | V    |  |
|   | L2 <sup>(4)</sup>   | -0.3 | 9.5 |      |  |
| Operating junct                               | tion temperature, T <sub>J</sub>  | -40  | 150 | °C   |  |
| Operating ambient temperature, T <sub>A</sub> |   | -40  | 85  | °C   |  |
| Storage tempe                                 | rature, T <sub>stg</sub>  | -65  | 150 | °C   |  |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) All voltage values are with respect to network ground pin.
- DC voltage rating.
- (4) AC voltage rating.

## 7.2 ESD Ratings

|             |  |  | VALUE | UNIT |
|-------------|--|--|-------|------|
|             | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±1500  |       |      |
| $V_{(ESD)}$ | Electrostatic discharge                                | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±700  | V    |

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

| See (1)          |  | MIN | NOM MAX | UNIT |
|------------------|--|-----|---------|------|
| $V_{IN}$         | Input voltage                          | 2.5 | 5.5     | ٧    |
| I <sub>OUT</sub> | Output current                         |     | 0.5     | Α    |
| L                | Inductance (2)                         | 1   | 1.5 2.2 | μΗ   |
| C <sub>OUT</sub> | Output capacitance (3)                 | 10  |         | μF   |
| T <sub>A</sub>   | Operating ambient temperature          | -40 | 85      | °C   |
| TJ               | Operating virtual junction temperature | -40 | 125     | °C   |

- (1) Refer to the Application Information section for further information
- (2) Effective inductance value at operating condition. The nominal value given matches a typical inductor to be chosen to meet the inductance required.
- (3) Due to the DC bias effect of ceramic capacitors, the effective capacitance is lower then the nominal value when a voltage is applied. This is why the capacitance is specified to allow the selection of the nominal capacitor required with the DC bias effect for this type of capacitor. The nominal value given matches a typical capacitor to be chosen to meet the minimum capacitance required.

## 7.4 Thermal Information

|                        |  | TPS6    |         |      |
|------------------------|--|---------|---------|------|
|                        | THERMAL METRIC <sup>(1)</sup>                | WCSP    | RMW     | UNIT |
|                        |  | 12 PINS | 12 PINS |      |
| $R_{\theta JA}$        | Junction-to-ambient thermal resistance       | 89.9    | 37.3    | °C/W |
| $R_{\theta JC(top)}$   | Junction-to-case (top) thermal resistance    | 0.7     | 30.4    | °C/W |
| $R_{\theta JB}$        | Junction-to-board thermal resistance         | 43.9    | 8.0     | °C/W |
| ΨЈТ                    | Junction-to-top characterization parameter   | 2.9     | 0.4     | °C/W |
| ΨЈВ                    | Junction-to-board characterization parameter | 43.7    | 7.8     | °C/W |
| R <sub>0</sub> JC(bot) | Junction-to-case (bottom) thermal resistance | n/a     | 2.5     | °C/W |

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



## 7.5 Electrical Characteristics

 $V_{IN} = 3.6 \text{ V}$ ,  $T_{J} = -40 ^{\circ}\text{C}$  to 125  $^{\circ}\text{C}$ , typical values are at  $T_{A} = 25 ^{\circ}\text{C}$  (unless otherwise noted)

|                          | PARAMETER                                      |                       | TEST CONDITIONS  | MIN   | TYP  | MAX  | UNIT |
|--------------------------|--|-----------------------|--|-------|------|------|------|
| SUPPLY                   |  |                       |  |       |      | •    |      |
| V <sub>IN</sub>          | Input voltage range                            |                       |  | 2.5   |      | 5.5  | V    |
| V <sub>IN_Min</sub>      | Minimum input voltage to turn of               | n in full load        | I <sub>OUT</sub> = 500 mA  |       | 2.7  |      | V    |
| I <sub>OUT</sub>         | Output current <sup>(1)</sup>                  |                       | $I_{LIMO} = V_{IH}, I_{LIM1} = V_{IH},$  |       | 500  |      | mA   |
| I <sub>Q</sub>           | Quiescent current (2)                          | V <sub>IN</sub>       | $I_{OUT}$ = 0 mA, EN = $V_{IN}$ = 3.6 V, $V_{OUT}$ = 3.3 V   |       | 43   | 65   | Δ    |
| 'Q                       | Quiescent current V                            | V <sub>OUT</sub>      | $\begin{split} I_{OUT} &= 0 \text{ mA, EN} = V_{IN} = 3.6 \text{ V,} \\ V_{OUT} &= 3.3 \text{ V} \end{split}$                |       |      | 10   | μΑ   |
| I <sub>sd</sub>          | Shutdown current (2)                           |                       | EN = 0 V   |       | 0.1  | 1    | μΑ   |
| UVLO <sub>TH</sub>       | Undervoltage lockout threshold                 |                       | V <sub>IN</sub> falling  | 1.6   | 1.7  | 1.8  | V    |
| UVLO <sub>hys</sub>      | Undervoltage lockout hysteresi                 | 5                     |  |       | 200  |      | mV   |
| $T_{SD}$                 | Thermal shutdown                               |                       | Temperature rising   |       | 140  |      | °C   |
| T <sub>SD</sub> (hys)    | Thermal shutdown hysteresis                    |                       |  |       | 20   |      | °C   |
| LOGIC SIGN               | NALS EN, I <sub>LIMO</sub> , I <sub>LIM1</sub> |                       | · · · · · · · · · · · · · · · · · · ·  |       |      |      |      |
| V <sub>IH</sub>          | High level input voltage                       |                       | V <sub>IN</sub> = 2.5 V to 5.5 V   | 1.2   |      |      | V    |
| V <sub>IL</sub>          | Low level voltage Input Voltage                |                       | V <sub>IN</sub> = 2.5 V to 5.5 V   |       |      | 0.3  | V    |
| I <sub>lkg</sub>         | Input leakage current                          |                       | $PFM / PWM, EN, I_{LIM0}, I_{LIM1} = GND or V_{IN}$  |       | 0.01 | 0.1  | μΑ   |
| POWER GO                 | OD   |                       |  |       |      |      |      |
| $V_{OL}$                 | Low level voltage                              |                       | $I_{sink} = 100 \mu A$   |       |      | 0.3  | V    |
| $I_{PG}$                 | PG sinking current                             |                       | V = 0.3 V  |       |      | 0.1  | mA   |
| I <sub>lkg</sub>         | Input leakage current                          |                       | $V_{PG} = 3.6 \text{ V}$   |       | 0.01 | 0.1  | μΑ   |
| OUTPUT                   |  |                       |  |       |      |      |      |
| $V_{OUT}$                | Output voltage range                           |                       |  | 2.5   |      | 5.5  | V    |
| $V_{FB}$                 | TPS63050 feedback regulation                   | voltage               |  |       | 8.0  |      | V    |
| $V_{FB}$                 | TPS63050 feedback voltage ac                   | curacy                | PWM mode   | -1.1% |      | 1.1% |      |
| $V_{FB}$                 | TPS63050 feedback voltage ac                   | curacy <sup>(3)</sup> | PFM mode   | -1%   |      | 3%   |      |
| V <sub>OUT</sub>         | TPS63051 output voltage accu                   | racy                  | PWM mode   | 3.27  | 3.3  | 3.34 | V    |
| V <sub>OUT</sub>         | TPS63051 output voltage accu                   | racy <sup>(3)</sup>   | PFM mode   | 3.27  | 3.3  | 3.39 | V    |
| I <sub>PWM-&gt;PFM</sub> | Minimum output current to ente                 | r PFM mode            | V <sub>IN</sub> = 3 V; V <sub>OUT</sub> = 3.3 V  |       | 150  |      | mA   |
| I <sub>FB</sub>          | TPS63050 feedback input bias                   | current               | V <sub>FB</sub> = 0.8 V  |       | 10   | 100  | nA   |
|                          | Input high-side FET on-resistar                | ice                   | I <sub>SW</sub> = 500 mA   |       | 145  |      | mΩ   |
| Б                        | Output high-side FET on-resist                 | ance                  | I <sub>SW</sub> = 500 mA   |       | 95   |      | mΩ   |
| R <sub>DS(on)</sub>      | Input low-side FET on-resistance               | е                     | I <sub>SW</sub> = 500 mA   |       | 170  |      | mΩ   |
|                          | Output low-side FET on-resista                 | nce                   | I <sub>SW</sub> = 500 mA   |       | 115  |      | mΩ   |
|                          | •  |                       | $I_{LIM0} = V_{IH}, I_{LIM1} = V_{IH}, V_{IN} = 2.7 \text{ V to 3}$ V, $V_{OUT} = 3 \text{ V}$                               | 480   |      | 1240 | mA   |
| I <sub>IN_MAX</sub>      | Input current-limit boost mode                 |                       | $\begin{split} I_{LIM0} &= V_{IH}, \ I_{LIM1} = V_{IH}, V_{IN} = 2.7 \ V \ to \\ 3.3 \ V, \ V_{OUT} &= 3.3 \ V, \end{split}$ | 550   |      | 1400 | mA   |
|                          |  |                       | $\begin{split} I_{LIM0} &= V_{IH}, \ I_{LIM1} = V_{IH}, V_{IN} = 2.7 \ V \ to \\ 4.5 \ V, \ V_{OUT} &= 4.5 \ V, \end{split}$ | 630   |      | 1950 | mA   |

<sup>(1)</sup> For minimum and maximum output current in a specific working point see Figure 1 and Figure 2; and Equation 1 through Equation 4.

<sup>(2)</sup> Conditions:  $T_J = -40^{\circ}C$  to 85°C

<sup>(3)</sup> Conditions: f = 2.5 MHz,  $L = 1.5 \mu\text{H}$ ,  $C_{OUT} = 10 \mu\text{F}$ 



## **Electrical Characteristics (continued)**

 $V_{IN} = 3.6 \text{ V}$ ,  $T_J = -40 ^{\circ}\text{C}$  to 125  $^{\circ}\text{C}$ , typical values are at  $T_A = 25 ^{\circ}\text{C}$  (unless otherwise noted)

|                    | PARAMETER  | TEST CONDITIONS  | MIN TYP                  | MAX | UNIT |
|--------------------|--|--|--------------------------|-----|------|
|                    |  | $\begin{array}{l} I_{LIM0} = V_{IL},\ I_{LIM1} = V_{IL},\\ V_{IN} = 3\ V, V_{OUT} = 3.3\ V,\ (Available\ for\ DBGA\ only) \end{array}$         | 0.4×I <sub>IN_MAX</sub>  |     |      |
| I <sub>SS_IN</sub> | Programmable inrush current limit <sup>(4)</sup> | $\begin{array}{l} I_{LIM0} = V_{IH}, \ I_{LIM1} = V_{IL}, \\ V_{IN} = 3 \ V, V_{OUT} = 3.3 \ V, \ (Available \ for \ DBGA \ only) \end{array}$ | 0.5×I <sub>IN_MAX</sub>  |     | mA   |
|                    |  | $I_{LIM0} = V_{IL}, I_{LIM1} = V_{IH},$<br>$V_{IN} = 3 V, V_{OUT} = 3.3 V$   | 0.65×I <sub>IN_MAX</sub> |     |      |
|                    |  | $I_{LIM0} = V_{IH}, I_{LIM1} = V_{IH},$<br>$V_{IN} = 3 V, V_{OUT} = 3.3 V$   | I <sub>IN_MAX</sub>      |     |      |
| I <sub>SS</sub>    | Soft-start current TPS63051                      |  | 1                        |     | μА   |
| I <sub>SS</sub>    | Soft-start current TPS63050                      |  | 3.2                      |     | μА   |
|                    | Line regulation                                  | $V_{\rm IN}$ = 2.5 V to 5.5 V, $I_{\rm OUT}$ = 500 mA, PWM mode  | 0.963                    |     | mV/V |
|                    | Load regulation                                  | $V_{\text{IN}}$ = 3.6 V, $I_{\text{OUT}}$ = 0 mA to 500 mA, PWM mode   | 4                        |     | mV/A |

<sup>(4)</sup> For variation of this parameter with Input voltage see Figure 3.

# 7.6 Switching Characteristics

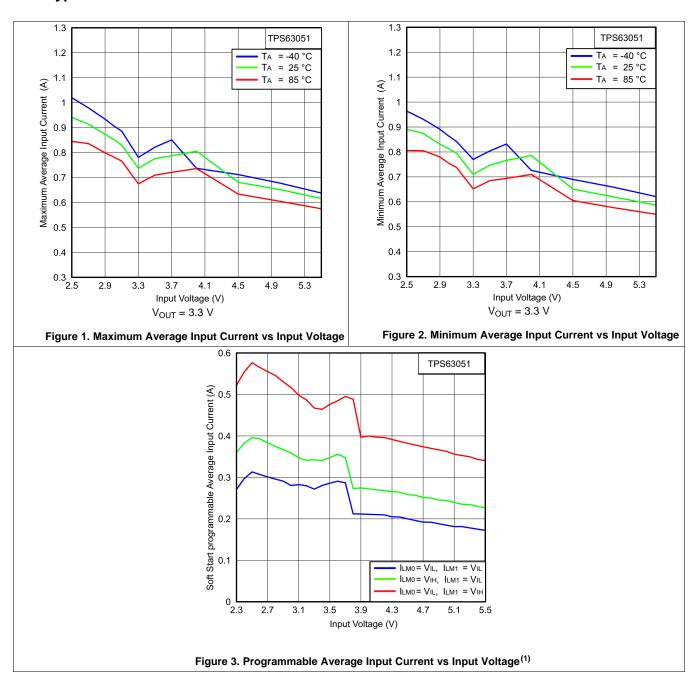
 $V_{IN} = 3.6 \text{ V}$ ,  $T_{J} = -40 ^{\circ}\text{C}$  to 125  $^{\circ}\text{C}$ , typical values are at  $T_{A} = 25 ^{\circ}\text{C}$  (unless otherwise noted)

|                               | PARAMETER           | TEST CONDITIONS  | MIN | TYP | MAX | UNIT |
|-------------------------------|---------------------|--|-----|-----|-----|------|
| OUTPUT                        |                     |  |     |     |     |      |
| fs                            | Switching frequency |  |     | 2.5 |     | MHz  |
| t <sub>SS</sub> Softstart tim | Softatart time      | $V_{OUT}$ = EN = low to high, SS = floating, Buck mode $V_{IN}$ = 3.6 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA <sup>(1)</sup>  | 280 |     |     |      |
|                               | Solisian time       | $V_{OUT}$ = EN = low to high, SS = floating, Boost mode $V_{IN}$ = 2.5 V, $V_{OUT}$ = 3.3 V, $I_{OUT}$ = 500 mA <sup>(1)</sup> | 600 |     |     | μs   |
| t <sub>d</sub>                | Start up delay      | Time from when EN = high to when device starts switching   | 100 |     |     | μs   |

<sup>(1)</sup> For variation of this parameter with Input voltage see Figure 3.



## 7.7 Typical Characteristics



(1) All options only available with the DSBGA package. For VQFN package ILIM1 is internally connected to voltage level > V<sub>IH</sub>

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## **Detailed Description**

#### Overview

The TPS6305x devices use 4 internal N-channel MOSFETs to maintain synchronous power conversion at all possible operating conditions. This enables the device to keep high efficiency over the complete input voltage and output power range. To regulate the output voltage at all possible input voltage conditions, the device automatically switches from buck operation to boost operation and back as required by the configuration. It always uses one active switch, one rectifying switch, one switch held on, and one switch held off. Therefore, it operates as a buck converter when the input voltage is higher than the output voltage, and as a boost converter when the input voltage is lower than the output voltage. There is no mode of operation in which all 4 switches are switching at the same time. Keeping one switch on and one switch off eliminates their switching losses. The RMS current through the switches and the inductor is kept at a minimum, to minimize switching and conduction losses. Controlling the switches this way allows the converter to always keep higher efficiency.

The device provides a seamless transition from buck to boost or from boost to buck operation.

# 8.2 Functional Block Diagrams

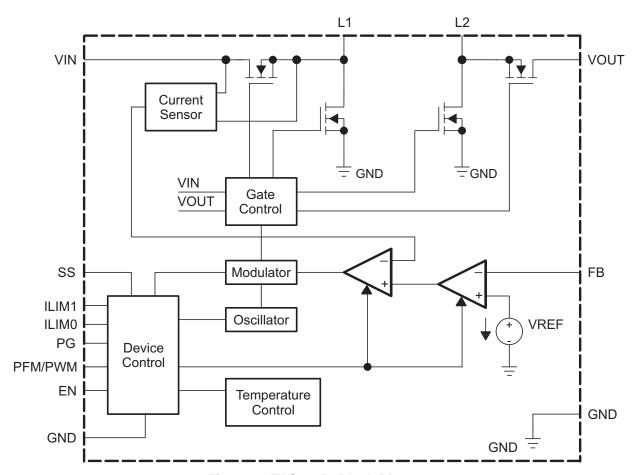


Figure 4. TPS63050 Block Diagram

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# **Functional Block Diagrams (continued)**

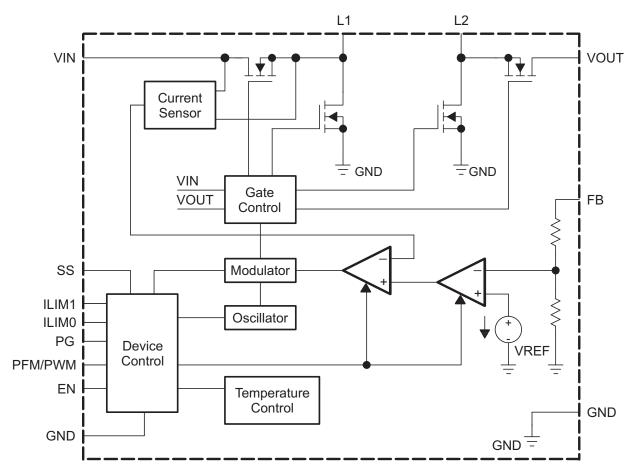


Figure 5. TPS63051 Block Diagram

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## 8.3 Feature Description

#### 8.3.1 Power Good

The TPS6305x devices have a PG output. The power good goes high impedance once the output is above 95% of the nominal voltage, and is driven low once the output voltage falls below typically 90% of the nominal voltage. The PG pin is an open drain output and is specified to sink up to 0.1 mA. The power good output requires a pullup resistor connecting to any voltage rail less than 5.5 V. The power good is valid as long as the converter is enabled and  $V_{\text{IN}}$  is present. The power good goes low when the device is in undervoltage lockout, in thermal shutdown or in current limit.

If EN is pulled low and one of the pins  $I_{LIM0}$  or  $I_{LIM1}$  is high, then the PG pin is low. If both pins,  $I_{LIM0}$  and  $I_{LIM1}$  are low, the PG is open drain. In this case the PG pin, follows its pullup voltage. If this is not desired, one of the two pins  $I_{LIM0}$  or  $I_{LIM1}$ , must be set high. Table 1 lists the PG pin functionality.

EN ILIM1 **ILIMO** PG 0 0 0 1 0 0 0 0 1 0 0 0 0 Open Drain

**Table 1. Power Good Settings** 

## 8.3.2 Overvoltage Protection

Overvoltage protection is implemented to limit the maximum output voltage. In case of overvoltage condition, the voltage amplifier regulates the output voltage to typically 6.7 V.

## 8.3.3 Undervoltage Lockout (UVLO)

To avoid mis-operation of the device at low input voltages, an undervoltage lockout is included. UVLO shuts down the device at input voltages lower than typically 1.7 V with a 200-mV hysteresis.

#### 8.3.4 Thermal Shutdown

The device goes into thermal shutdown once the junction temperature exceeds typically 140°C with a 20°C hysteresis.

#### 8.3.5 Soft Start

To minimize inrush current and output voltage overshoot during start up, the device has a soft start. At turn on, the input current raises monotonically until the output voltage reaches regulation. The TPS6305x devices charge the soft start capacitor, at the SS pin, with a constant current of typically 1  $\mu$ A. The input current follows the current used to charge the capacitor at the SS pin. The soft start operation is completed once the voltage at the SS pin has reached typically 1.3 V. Figure 3 shows the value of the soft start capacitor in respect to the soft-start time.

The soft-start time is the time from when the EN pin is asserted to when the output voltage has reached 90% of its nominal value. There is typically a 100-µs delay time from EN pin assertion to the start of the switching activity. The soft-start time depends on the load current, the input voltage, and the output capacitor. The soft-start time in boost mode is longer then the time in buck mode and it also depends on the load current, input voltage and output capacitor.

The soft-start time in Figure 3 is referred to typical application with 10-µF effective output capacitance.

The inductor current is able to increase and always assure a soft start unless a real short circuit is applied at the output.

## 8.3.6 Short Circuit Protection

The TPS6305x devices provide short circuit protection. When the output voltage does not increase above 1.2 V, a short circuit is detected and the output current is limited to 1.5 A.



#### 8.4 Device Functional Modes

#### 8.4.1 Control Loop Description

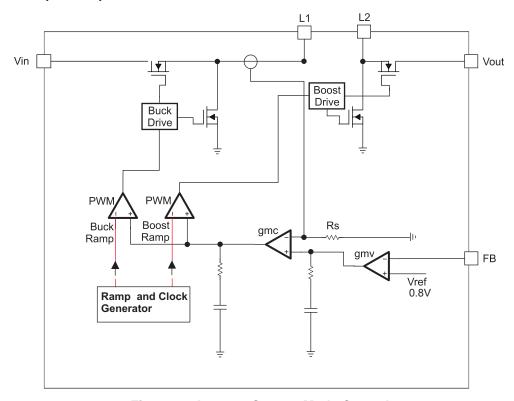


Figure 6. Average Current Mode Control

The controller circuit of the device is based on an average current mode topology. The average inductor current is regulated by a fast current regulator loop which is controlled by a voltage control loop. Figure 6 shows the control loop.

The noninverting input of the transconductance amplifier,  $gm_v$ , is assumed to be constant. The output of  $gm_v$  defines the average inductor current. The inductor current is reconstructed by measuring the current through the high side buck MOSFET. This current corresponds exactly to the inductor current in boost mode. In buck mode the current is measured during the on time of the same MOSFET. During the off time, the current is reconstructed internally starting from the peak value at the end of the on time cycle. The average current and the feedback from the error amplifier  $gm_v$  forms the correction signal  $gm_c$ . This correction signal is compared to the buck and the boost sawtooth ramp giving the PWM signal. Depending on which of the two ramps the  $gm_c$  output crosses either the Buck or the Boost stage is initiated. When the input voltage is close to the output voltage, one buck cycle is always followed by a boost cycle. In this condition, no more than three cycles in a row of the same mode are allowed. This control method in the buck-boost region ensures a robust control and the highest efficiency.

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## **Device Functional Modes (continued)**

## 8.4.2 Power Save Mode Operation

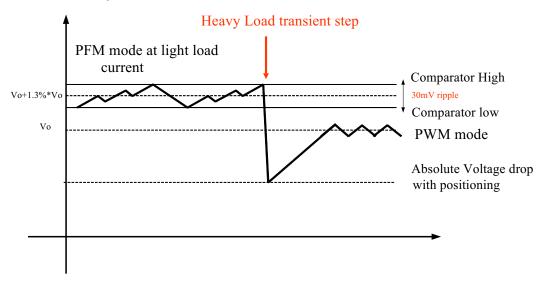


Figure 7. Power Save Mode Operation

Depending on the load current, the device works in PWM mode at load currents of approximately 350 mA or higher to provide the best efficiency over the complete load range. At lighter loads, the device switches automatically into Power Save Mode to reduce power consumption and extend battery life. The PFM/PWM pin is used to select between the two different operation modes. To enable Power Save Mode, the PFM/PWM pin must be set low.

During Power Save Mode, the part operates with a reduced switching frequency and lowest supply current to maintain high efficiency. The output voltage is monitored with a comparator at every clock cycle by the thresholds comp low and comp high. When the device enters Power Save Mode, the converter stops operating and the output voltage drops. The slope of the output voltage depends on the load and the output capacitance. When the output voltage reaches the comp low threshold, at the next clock cycle the device ramps up the output voltage again, by starting operation. Operation can last for one or several pulses until the comp high threshold is reached. At the next clock cycle, if the load is still lower than 150 mA, the device switches off again and the same operation is repeated. If at the next clock cycle the load is above 150 mA, the device automatically switches to PWM mode.

To keep high efficiency in PFM mode, there is only one comparator active to keep the output voltage regulated. The AC ripple in this condition is increased, compared to the PWM mode. The amplitude of this voltage ripple in the worst case scenario is 50 mV peak to peak, (typically 30 mV peak-to-peak), with 10  $\mu$ F of effective output capacitance. To avoid a critical voltage drop when switching from 0 A to full load, the output voltage in PFM mode is typically 1.5% above the nominal value in PWM mode. This is called Dynamic Voltage Positioning and allows the converter to operate with a small output capacitor and still have a low absolute voltage drop during heavy load transients.

Power Save Mode is disabled by setting the PFM/PWM pin high.

## 8.4.3 Adjustable Current Limit

The TPS6305x devices have an internal user programmable current limit that monitors the input current during start-up. This prevents high inrush current protecting the device and the application. During start-up the input current does not exceed the current limit that is set by I<sub>LIM0</sub> pin and I<sub>LIM1</sub> pin. Depending on the logic level applied at these two pins, switching between four different current limit-levels is possible. The variation of those values over input voltage and temperature is shown in Figure 1 through Figure 2. Adjusting the soft-start time further using the soft-start capacitor is possible.

 $I_{LIM0}$  and  $I_{LIM1}$  set the current limit as listed in Table 2.

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# **Device Functional Modes (continued)**

#### **Table 2. Adjustable Current Limit**

| ILIM1 | ILIMO | CURRENT LIMIT SET (WCSP)   | CURRENT LIMIT SET (HotRod) |
|-------|-------|----------------------------|----------------------------|
| Low   | Low   | 0.4 × I <sub>IN_MAX</sub>  | Not Available              |
| Low   | High  | 0.5 × I <sub>IN_MAX</sub>  | Not Available              |
| High  | Low   | 0.65 × I <sub>IN_MAX</sub> | 0.65 × I <sub>IN_MAX</sub> |
| High  | High  | I <sub>IN_MAX</sub>        | I <sub>IN_MAX</sub>        |

The I<sub>LIM0</sub>, I<sub>LIM1</sub> pins can be changed during operation.

Given the curves provided in Figure 1 through Figure 2, calculating the output current in the different condition in boost mode is possible using Equation 1 and Equation 2 and in buck mode using Equation 3 and Equation 4.

Duty Cycle Boost 
$$D = \frac{V_{OUT} - V_{IN}}{V_{OUT}}$$
Output Current Boost 
$$I_{Out} = \eta \times I_{IN} (1-D)$$
(1)

#### where

- η = Estimated converter efficiency (use the number from the efficiency curves or 0.9 as an assumption)
- I<sub>IN</sub> = Minimum average input current (Figure 2 to Figure 2) (2)

Duty Cycle Buck 
$$D = \frac{V_{OUT}}{V_{IN}}$$
Output Current Buck 
$$I_{OUT} = ( \eta \times I_{IN} ) / D$$
(3)

## where

For η, use the number from the efficiency curves or 0.9 as an assumption.

#### 8.4.4 Device Enable

The device starts operation when the EN pin is set high. The device enters shutdown mode when the EN pin is set low. In shutdown mode, the regulator stops switching, all internal control circuitry is switched off, and the load is disconnected from the input.



# 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers must validate and test their design implementation to confirm system functionality.

## 9.1 Application Information

The TPS6305x is a high efficiency, low quiescent current buck-boost converter suitable for applications where the input voltage is higher or lower than the output voltage. Continuous output current can go as high as 500 mA in boost mode and as high as 1 A in buck mode. The maximum average current in the switches is limited to a typical value of 1 A.

The efficiency measurements

## 9.2 Typical Application

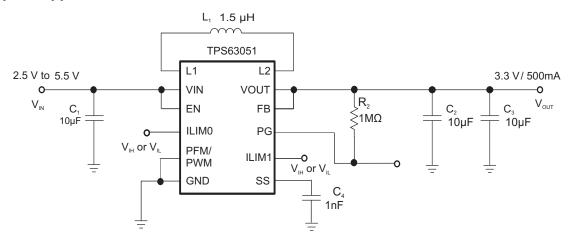


Figure 8. Parameter Measurement Circuit (WCSP)

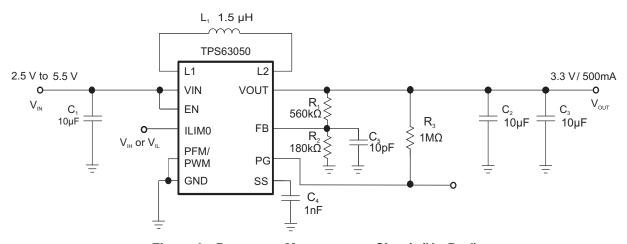


Figure 9. Parameter Measurement Circuit (HotRod)

## 9.2.1 Design Requirements

The design guidelines provide a component selection to operate the device within the recommended operating conditions.



# **Typical Application (continued)**

## 9.2.2 Detailed Design Procedure

## 9.2.2.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS63050 device with the WEBENCH® Power Designer.

Click here to create a custom design using the TPS63051 device with the WEBENCH® Power Designer.

- Start by entering the input voltage (V<sub>IN</sub>), output voltage (V<sub>OUT</sub>), and output current (I<sub>OUT</sub>) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- · Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

Get more information about WEBENCH tools at www.ti.com/WEBENCH.

The first step is the selection of the output filter components, listed in Table 3. To simplify this process, Table 4 outlines possible inductor and capacitor value combinations.

**Table 3. Components for Application Characteristic Curves** 

| REFERENCE  | DESCRIPTION  | MANUFACTURER                                    |  |  |  |  |
|------------|--|---|--|--|--|--|
|            | TPS6305x   | Texas Instruments                               |  |  |  |  |
| L1         | 1.5 μH, 2.1 A, 108 mΩ  | 1269AS-H-1R5M, TOKO                             |  |  |  |  |
| C1, C2, C3 | 10 μF, 6.3 V, 0603, X5R ceramic                                    | GRM188R60J106ME84D, Murata                      |  |  |  |  |
| C4         | C <sub>SS</sub>  |   |  |  |  |  |
| C5         | 10pF, only needed for the HotRod package version to filter gro     | ound noise when using external resistor divider |  |  |  |  |
| R1         | Depending on the output voltage of TPS6305x, 0 $\Omega$ with TPS6  | 3051  |  |  |  |  |
| R2         | Depending on the output voltage of TPS6305x, not used withTPS63051 |   |  |  |  |  |
| R3         | 1 ΜΩ   |   |  |  |  |  |

## 9.2.2.2 Output Filter Design

**Table 4. Matrix of Output Capacitor and Inductor Combinations** 

| NOMINAL                               | NOMINAL OUTPUT CAPACITOR VALUE [μF] <sup>(2)</sup> |      |    |    |     |  |  |  |  |  |  |
|---------------------------------------|--|------|----|----|-----|--|--|--|--|--|--|
| INDUCTOR<br>VALUE [µH] <sup>(1)</sup> | 10   | 20   | 44 | 66 | 100 |  |  |  |  |  |  |
| 1                                     |  |      | +  | +  | +   |  |  |  |  |  |  |
| 1.5                                   | +  | +(3) | +  | +  | +   |  |  |  |  |  |  |
| 2.2                                   |  |      | +  | +  | +   |  |  |  |  |  |  |

- (1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by 20% and -30%.
- (2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by 20% and -50%.

(3) Typical application. Other check mark indicates recommended filter combinations



#### 9.2.2.3 Inductor Selection

The inductor selection is affected by several parameter like inductor ripple current, output voltage ripple, transition point into power save mode, and efficiency. See Table 5 for typical inductors.

**Table 5. List of Recommended Inductors** 

| INDUCTOR VALUE | COMPONENT SUPPLIER (1) | SIZE (L × W × H mm) | Isat / DCR                           |
|----------------|------------------------|---------------------|--------------------------------------|
| 1 μΗ           | TOKO 1286AS-H-1R0M     | 2 × 1.6 × 1.2       | 2.1 A / 68 mΩ                        |
| 1.5 µH         | TOKO, 1286AS-H-1R5M    | 2 × 1.6 × 1.2       | $2.5~\text{A}$ / $95~\text{m}\Omega$ |
| 1.5 µH         | TOKO, 1269AS-H-1R5M    | 2.5 × 2 × 1         | 2.1 A / 90 mΩ                        |
| 2.2 µH         | TOKO 1286AS-H-2R2M     | 2 × 1.6 × 1.2       | 2 A / 160 mΩ                         |

<sup>(1)</sup> See the Third Party Product Disclaimer section.

For high efficiencies, the inductor must have a low dc resistance to minimize conduction losses. Especially at high-switching frequencies, the core material has a high impact on efficiency. When using small chip inductors, the efficiency is reduced mainly due to higher inductor core losses. This needs to be considered when selecting the appropriate inductor. The inductor value determines the inductor ripple current. The larger the inductor value, the smaller the inductor ripple current and the lower the conduction losses of the converter. Conversely, larger inductor values cause a slower load transient response. To avoid saturation of the inductor, the peak current for the inductor in steady state operation is calculated using Equation 6. Only the equation which defines the switch current in boost mode is shown, because this provides the highest value of current and represents the critical current value for selecting inductor.

Duty Cycle Boost 
$$D = \frac{V_{OUT} - V_{IN}}{V_{OUT}}$$

where

• D = Duty Cycle in Boost mode
$$I_{PEAK} = \frac{Iout}{\eta \times (1 - D)} + \frac{Vin \times D}{2 \times f \times L}$$
(5)

where

η = Estimated converter efficiency (use the number from the efficiency curves or 0.80 as an assumption)
 f = Converter switching frequency (typical 2.5MHz)
 L = Inductor value

## NOTE

The calculation must be done for the minimum input voltage that is possible to have in boost mode.

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. It's recommended to choose an inductor with a saturation current 20% higher than the value calculated using Equation 6. Possible inductors are listed in Table 5.

#### 9.2.2.4 Capacitor selection

#### 9.2.2.4.1 Input Capacitor

At least a  $10-\mu F$  input capacitor is recommended to improve line transient behavior of the regulator and EMI behavior of the total power supply circuit. An X5R or X7R ceramic capacitor placed as close as possible to the VIN and GND pins of the IC is recommended. This capacitance can be increased without limit.

#### 9.2.2.4.2 Output Capacitor

Use of small ceramic capacitors placed as close as possible to the VOUT and PGND pins of the IC, is recommended for the output capacitor. The recommended nominal output capacitance value is 10  $\mu$ F with a variance as outlined in Table 4.

There is also no upper limit for the output capacitance value. Larger capacitors causes lower output voltage ripple as well as lower output voltage drop during load transients.

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## 9.2.2.5 Setting the Output Voltage

When the adjustable output voltage version TPS63050 is used, the output voltage is set by the external resistor divider. The resistor divider must be connected between VOUT, FB and GND. When the output voltage is regulated properly, the typical value of the voltage at the FB pin is 800 mV. The current through the resistive divider must be 100 times greater than the current into the FB pin. The typical current into the FB pin is 0.1  $\mu$ A, and the voltage across the resistor between FB and GND, R<sub>2</sub>, is typically 800 mV. Based on these two values, the recommended value for R2 must be lower than 200 k $\Omega$ , in order to set the divider current at 3  $\mu$ A or higher. It is recommended to keep the value for this resistor in the range of 200 k $\Omega$ . The value of the resistor connected between VOUT and FB, R1, depending on the needed output voltage (V<sub>OUT</sub>), can be calculated using Equation 7:

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1\right)$$
 (7)

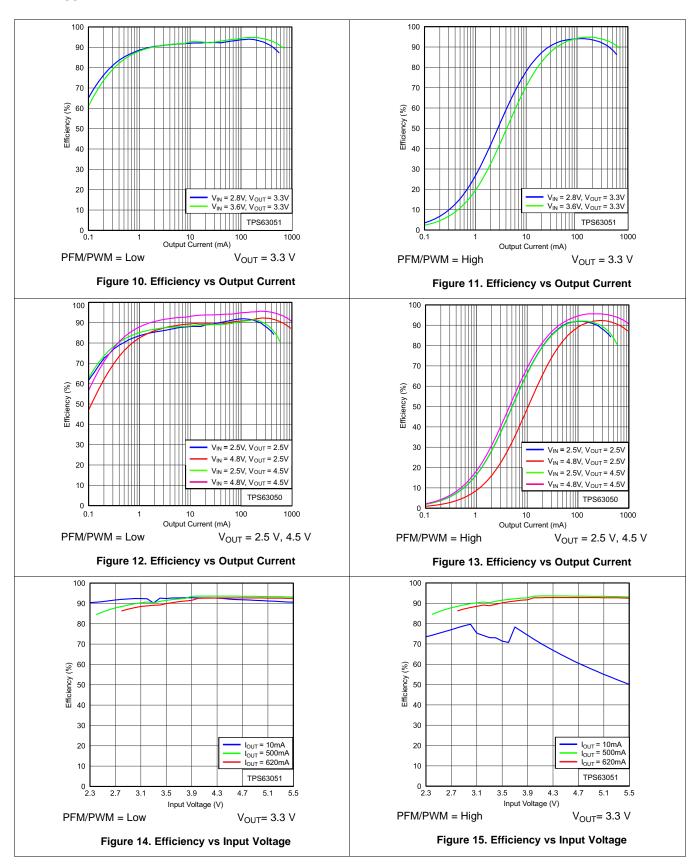
When using the HotRod package version of the TPS63050, it is recommended to add capacitor C<sub>5</sub>, as shown in Figure 9. The capacitor on the feedback node is required to help filtering ground noise and matching the efficiency result shown in the Application Curves paragraph.

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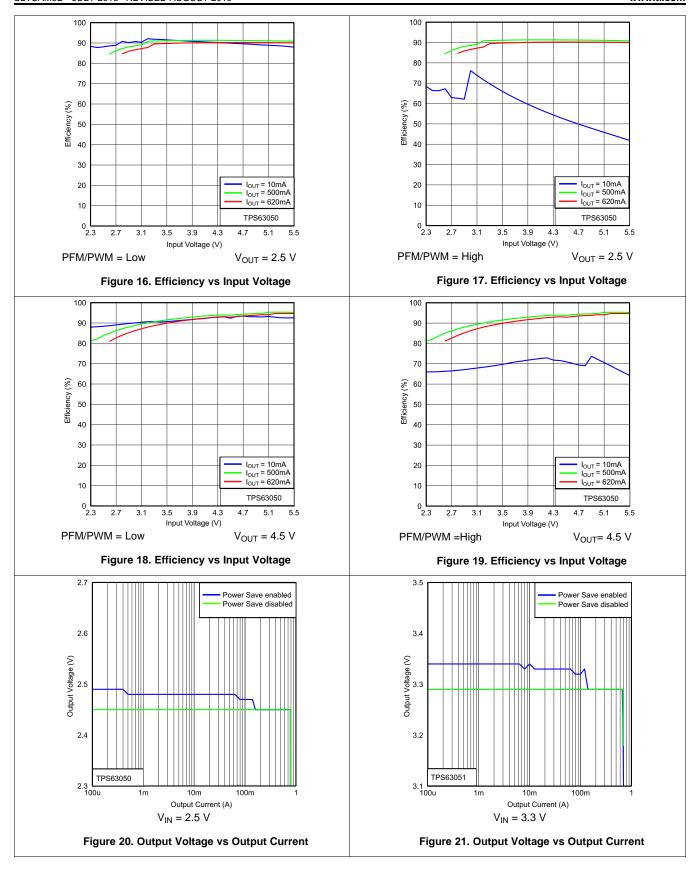
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## 9.2.3 Application Curves



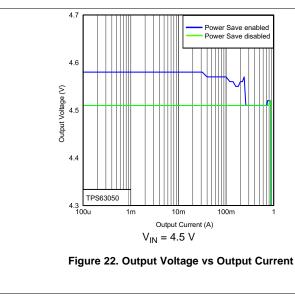




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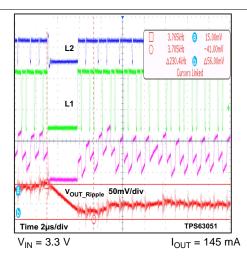
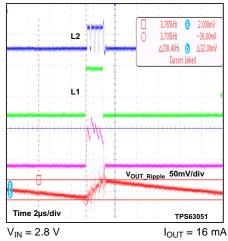


Figure 23. Output Voltage ripple in Buck-Boost mode and PFM to PWM transition





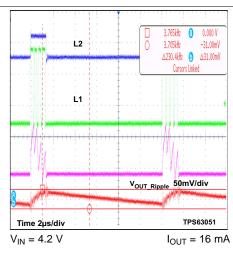
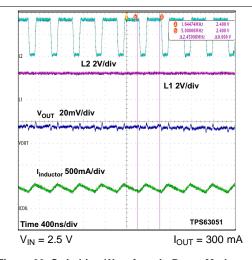
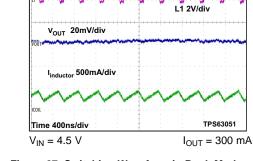


Figure 25. Output Voltage Ripple in Buck Mode and PFM to PWM Transition

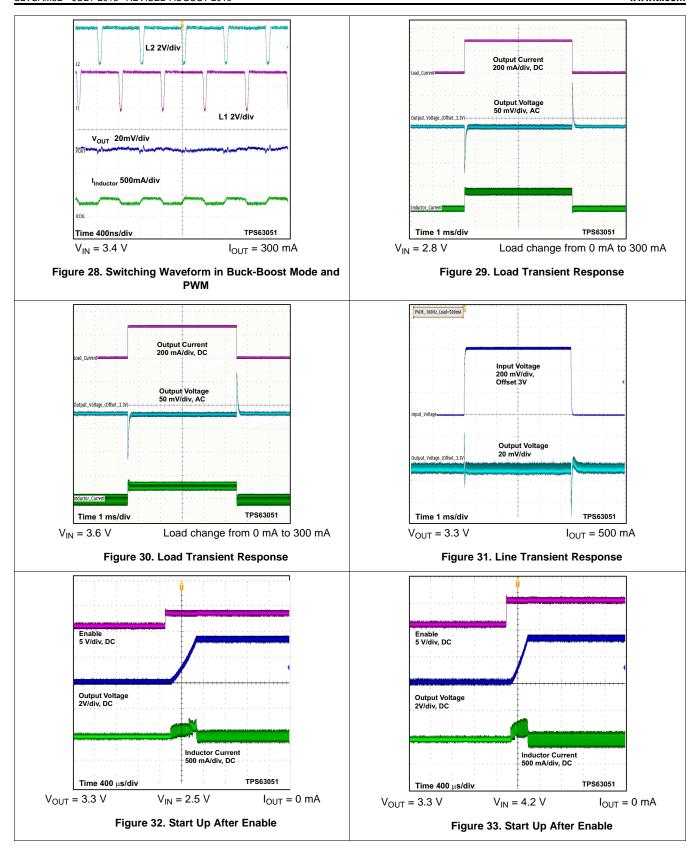




L2 2V/div

Figure 27. Switching Waveform in Buck Mode and PWM





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# 10 Power Supply Recommendations

The TPS6305x device family has no special requirements for its input power supply. The input power supply output current needs to be rated according to the supply voltage, output voltage and output current of the TPS6305x devices.

## 11 Layout

## 11.1 Layout Guidelines

The PCB layout is an important step to maintain the high performance of the TPS6305x devices.

- Place input and output capacitors as close as possible to the IC. Traces need to be kept short. Routing wide
  and direct traces to the input and output capacitor results in low-trace resistance and low parasitic inductance.
- Use a common-power GND.
- The sense trace connected to FB is signal trace. Keep these traces away from L1 and L2 nodes.
- For the HotRod package option it is important to add a capacitor between FB node and ground to filter ground noise and to match efficiency results documented in these datasheet.

## 11.2 Layout Example (WCSP)

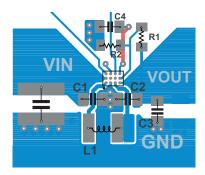


Figure 34. TPS6305x Layout (WCSP)

## 11.3 Layout Example (HotRod)

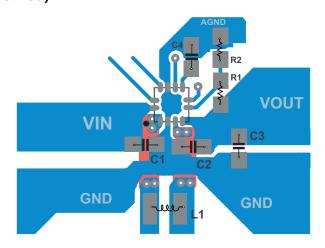


Figure 35. TPS6305x Layout (HotRod)

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#### 11.4 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the powerdissipation limits of a given component.

Two basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design
- · Introducing airflow in the system

For more details on how to use the thermal parameters, see the application notes: *Thermal Characteristics* (SZZA017), and *Semiconductor and IC Package Thermal Metrics* (SPRA953)

# 12 Device and Documentation Support

## 12.1 Custom Design With WEBENCH® Tools

Click here to create a custom design using the TPS63050 device with the WEBENCH® Power Designer.

Click here to create a custom design using the TPS63051 device with the WEBENCH® Power Designer.

- 1. Start by entering the input voltage (V<sub>IN</sub>), output voltage (V<sub>OUT</sub>), and output current (I<sub>OUT</sub>) requirements.
- 2. Optimize the design for key parameters such as efficiency, footprint, and cost using the optimizer dial.
- 3. Compare the generated design with other possible solutions from Texas Instruments.

The WEBENCH Power Designer provides a customized schematic along with a list of materials with real-time pricing and component availability.

In most cases, these actions are available:

- Run electrical simulations to see important waveforms and circuit performance
- Run thermal simulations to understand board thermal performance
- Export customized schematic and layout into popular CAD formats
- Print PDF reports for the design, and share the design with colleagues

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## 12.2 Device Support

## 12.2.1 Third-Party Products Disclaimer

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#### 12.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 6. Related Links

| PARTS    | PRODUCT FOLDER | SAMPLE & BUY | TECHNICAL DOCUMENTS | TOOLS & SOFTWARE | SUPPORT & COMMUNITY |
|----------|----------------|--------------|---------------------|------------------|---------------------|
| TPS63050 | Click here     | Click here   | Click here          | Click here       | Click here          |
| TPS63051 | Click here     | Click here   | Click here          | Click here       | Click here          |



# 12.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

## 12.6 Trademarks

E2E is a trademark of Texas Instruments.
WEBENCH is a registered trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

## 12.7 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.8 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: TPS63050 TPS63051

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#### PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type | Package   Pins     | Package qty   Carrier | RoHS | Lead finish/<br>Ball material | MSL rating/<br>Peak reflow | Op temp (°C) | Part marking (6) |
|-----------------------|------------|---------------|--------------------|-----------------------|------|-------------------------------|----------------------------|--------------|------------------|
| TPS63050RMWR          | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | Call TI   Nipdau              | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050RMWR.A        | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | Call TI                       | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050RMWT          | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | Call TI   Nipdau              | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050RMWT.A        | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | Call TI                       | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050RMWTG4        | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050RMWTG4.A      | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | F630             |
| TPS63050YFFR          | Active     | Production    | DSBGA (YFF)   12   | 3000   LARGE T&R      | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63050            |
| TPS63050YFFR.A        | Active     | Production    | DSBGA (YFF)   12   | 3000   LARGE T&R      | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63050            |
| TPS63050YFFT          | Active     | Production    | DSBGA (YFF)   12   | 250   SMALL T&R       | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63050            |
| TPS63050YFFT.A        | Active     | Production    | DSBGA (YFF)   12   | 250   SMALL T&R       | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63050            |
| TPS63051RMWR          | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | Call TI   Nipdau              | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051RMWR.A        | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | Call TI                       | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051RMWRG4        | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051RMWRG4.A      | Active     | Production    | VQFN-HR (RMW)   12 | 3000   LARGE T&R      | Yes  | NIPDAU                        | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051RMWT          | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | Call TI   Nipdau              | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051RMWT.A        | Active     | Production    | VQFN-HR (RMW)   12 | 250   SMALL T&R       | Yes  | Call TI                       | Level-1-260C-UNLIM         | -40 to 125   | F631             |
| TPS63051YFFR          | Active     | Production    | DSBGA (YFF)   12   | 3000   LARGE T&R      | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63051            |
| TPS63051YFFR.A        | Active     | Production    | DSBGA (YFF)   12   | 3000   LARGE T&R      | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63051            |
| TPS63051YFFT          | Active     | Production    | DSBGA (YFF)   12   | 250   SMALL T&R       | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63051            |
| TPS63051YFFT.A        | Active     | Production    | DSBGA (YFF)   12   | 250   SMALL T&R       | Yes  | SNAGCU                        | Level-1-260C-UNLIM         | -40 to 125   | 63051            |

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.



# PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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PACKAGE MATERIALS INFORMATION

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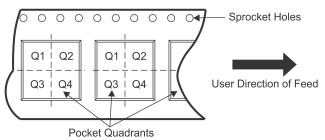
# TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

| Device       | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|--------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPS63050RMWR | VQFN-<br>HR     | RMW                | 12 | 3000 | 180.0                    | 8.4                      | 2.8        | 2.8        | 1.0        | 4.0        | 8.0       | Q2               |
| TPS63050RMWT | VQFN-<br>HR     | RMW                | 12 | 250  | 180.0                    | 8.4                      | 2.8        | 2.8        | 1.0        | 4.0        | 8.0       | Q2               |
| TPS63050YFFR | DSBGA           | YFF                | 12 | 3000 | 180.0                    | 8.4                      | 1.39       | 1.79       | 0.7        | 4.0        | 8.0       | Q1               |
| TPS63050YFFT | DSBGA           | YFF                | 12 | 250  | 180.0                    | 8.4                      | 1.39       | 1.79       | 0.7        | 4.0        | 8.0       | Q1               |
| TPS63051RMWR | VQFN-<br>HR     | RMW                | 12 | 3000 | 180.0                    | 8.4                      | 2.8        | 2.8        | 1.0        | 4.0        | 8.0       | Q2               |
| TPS63051RMWT | VQFN-<br>HR     | RMW                | 12 | 250  | 180.0                    | 8.4                      | 2.8        | 2.8        | 1.0        | 4.0        | 8.0       | Q2               |
| TPS63051YFFR | DSBGA           | YFF                | 12 | 3000 | 180.0                    | 8.4                      | 1.39       | 1.79       | 0.7        | 4.0        | 8.0       | Q1               |
| TPS63051YFFT | DSBGA           | YFF                | 12 | 250  | 180.0                    | 8.4                      | 1.39       | 1.79       | 0.7        | 4.0        | 8.0       | Q1               |

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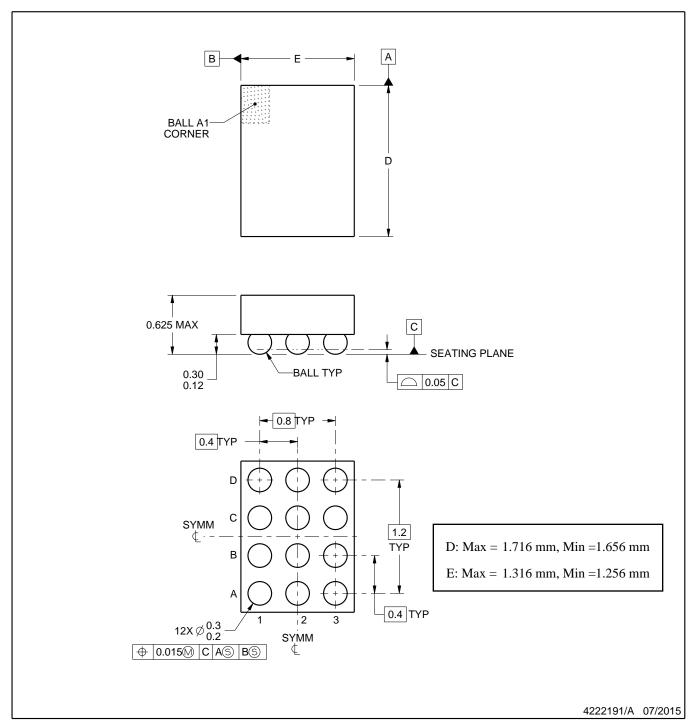


\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS63050RMWR | VQFN-HR      | RMW             | 12   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS63050RMWT | VQFN-HR      | RMW             | 12   | 250  | 182.0       | 182.0      | 20.0        |
| TPS63050YFFR | DSBGA        | YFF             | 12   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS63050YFFT | DSBGA        | YFF             | 12   | 250  | 182.0       | 182.0      | 20.0        |
| TPS63051RMWR | VQFN-HR      | RMW             | 12   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS63051RMWT | VQFN-HR      | RMW             | 12   | 250  | 182.0       | 182.0      | 20.0        |
| TPS63051YFFR | DSBGA        | YFF             | 12   | 3000 | 182.0       | 182.0      | 20.0        |
| TPS63051YFFT | DSBGA        | YFF             | 12   | 250  | 182.0       | 182.0      | 20.0        |



DIE SIZE BALL GRID ARRAY



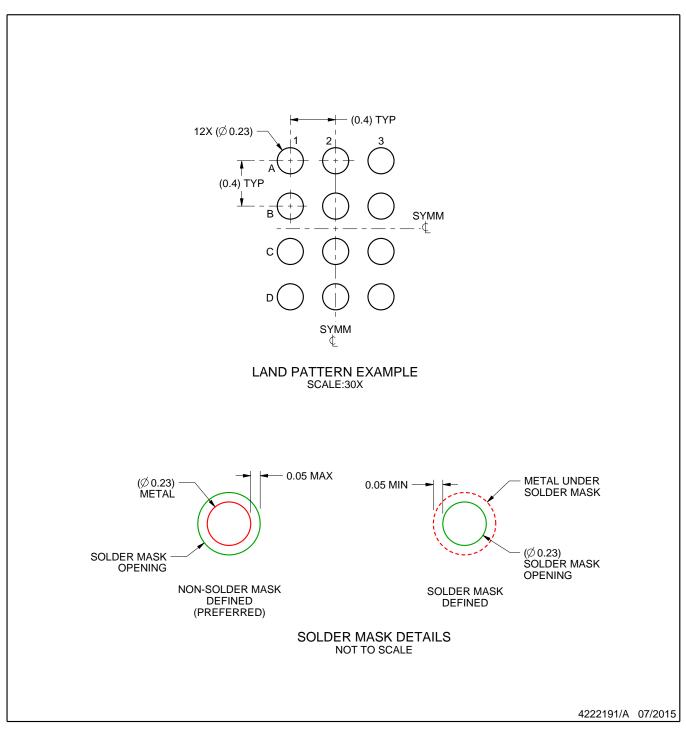
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

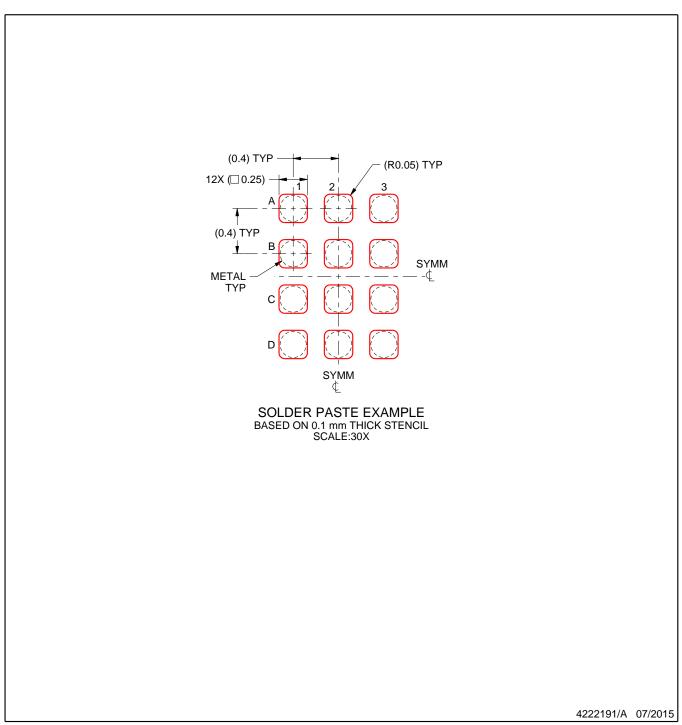


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



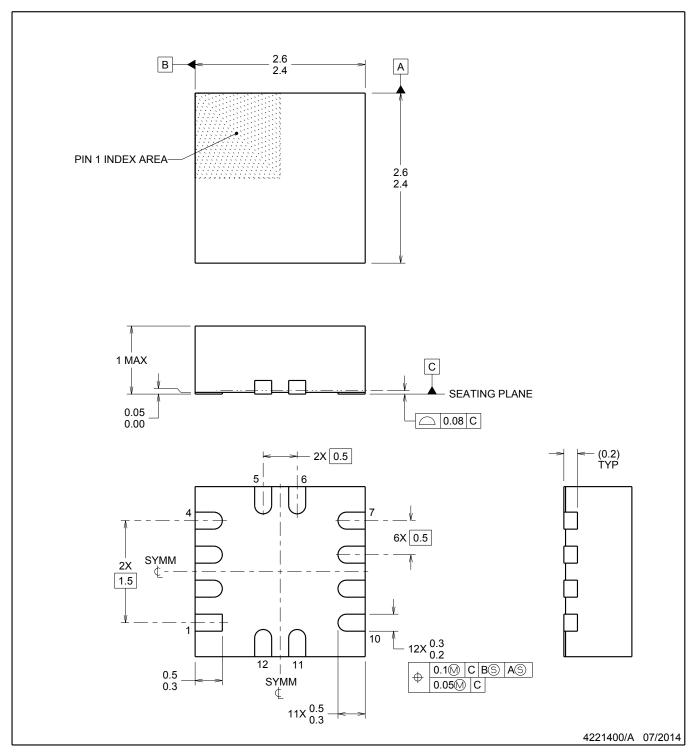
NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.





PLASTIC QUAD FLAT PACK - NO LEAD



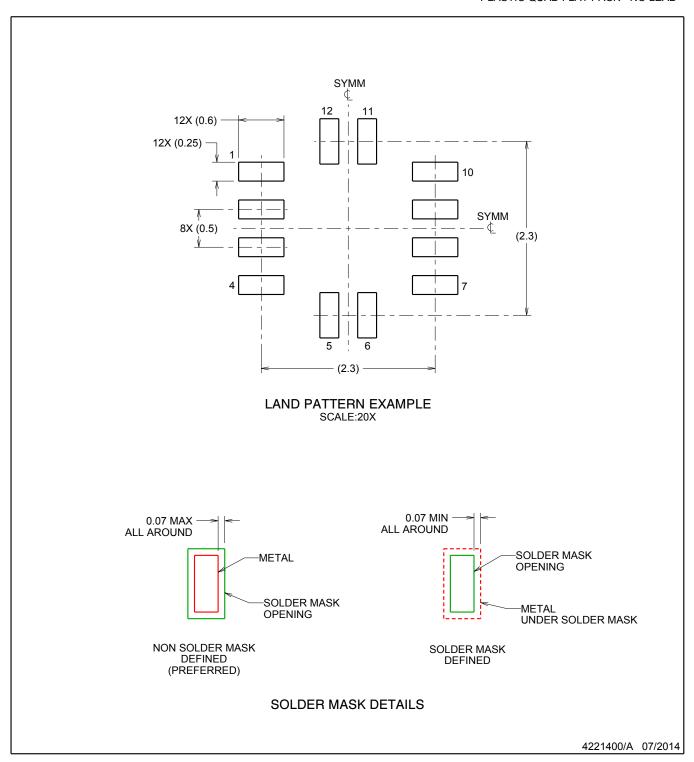
## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



PLASTIC QUAD FLAT PACK - NO LEAD

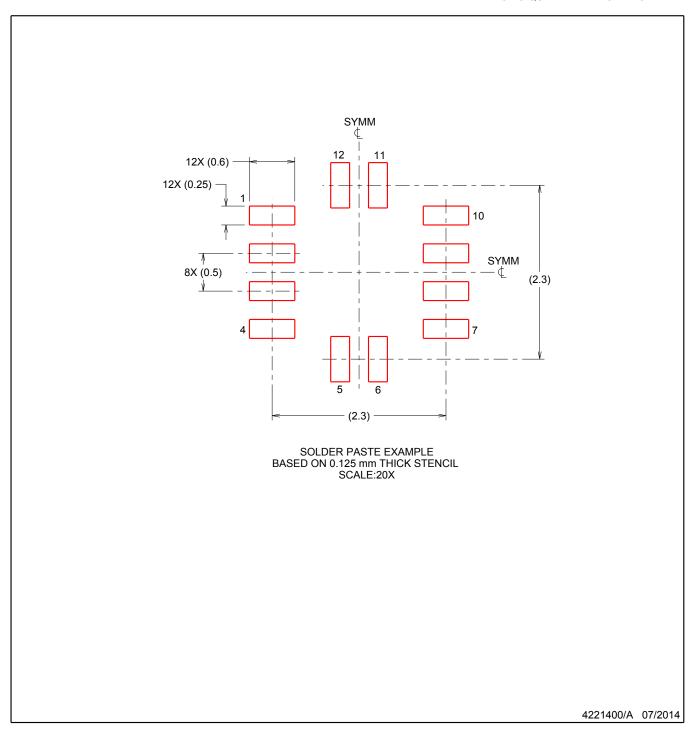


NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).



PLASTIC QUAD FLAT PACK - NO LEAD



## NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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